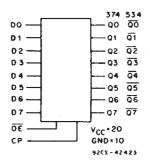


Data sheet acquired from Harris Semiconductor SCHS290



## Octal D-Type Flip-Flops, 3-State

Positive-Edge Triggered

CD54/74AC/ACT374 - Non-Inverting CD54/74AC/ACT534 - Inverting

### **Type Features:**

- Buffered inputs
- Typical propagation delay: 5 ns @ V<sub>CC</sub> = 5 V, T<sub>A</sub> = 25° C, C<sub>L</sub> = 50 pF

#### **FUNCTIONAL DIAGRAM**

•

The RCA-CD54/74AC374 and CD54/74AC534 and the CD54/74ACT374 and CD54/74ACT534 octal D-type, 3-state, positive-edge triggered flip-flops use the RCA ADVANCED CMOS technology. The eight flip-flops enter data into their registers on the LOW-to-HIGH transition of the clock (CP). The Output Enable (OE) controls the 3-state outputs and is independent of the register operation. When the Output Enable (OE) is HIGH, the outputs are in the high-impedance state. The CD54/74AC/ACT374 and CD54/74AC/ACT534 share the same pin configurations, but the CD54/74AC/ACT374 outputs are non-inverted while the CD54/74AC/ACT534 devices have inverted outputs. (For flow-through pin configurations, see CD54/74AC/ACT564 and CD54/74AC/ACT574.)

The CD74AC/ACT374 and CD74AC/ACT534 are supplied in 20-lead dual-in-line plastic packages (E suffix) and in 20-lead dual-in-line small-outline plastic packages (M suffix). Both package types are operable over the following temperature ranges: Commercial (0 to 70°C); Industrial (-40 to +85°C); and Extended Industrial/Military (-55 to +125°C).

The CD54AC/ACT374 and CD54AC/ACT534, available in chip form (H suffix), are operable over the -55 to +125×C temperature range.

### **Family Features:**

- Exceeds 2-kV ESD Protection MIL-STD-883, Method 3015
- SCR-Latch-up-resistant CMOS process and circuit design
- Speed of bipolar FAST\*/AS/S with significantly reduced power consumption
- Balanced propagation delays
- AC types feature 1.5-V to 5.5-V operation and balanced noise immunity at 30% of the supply
- ± 24-mA output drive current Fanout to 15 FAST\* ICs Drives 50-ohm transmission lines

\*FAST is a Registered Trademark of Fairchild Semiconductor Corp.

#### TRUTH TABLE

	INPUTS			PUTS
		374	534	
ŌE	СР	Dn	Qn	Qn
L		Н	Н	L
L		L	L	Н
L	L	Х	QO	QO
Н	Х	Х	Z	Z

H = High level (steady state)

L = Low level (steady state)

X = Don't care

\_\_\_ = Transition from low to high level

QO = The level of Q before the indicated steady-state input conditions were established

Z = High impedance

MAXIMUM RATINGS, Absolute-Maximum Values:
DC SUPPLY-VOLTAGE (Vcc)0.5 to 6 V
DC INPUT DIODE CURRENT. $I_{iK}$ (for $V_1 < -0.5 \text{ V}$ or $V_1 > V_{CC} + 0.5 \text{ V}$ )
DC OUTPUT DIODE CURRENT. low (for $V_0 < -0.5 \text{ V}$ or $V_0 > V_{cc} + 0.5 \text{ V}$ ) $\pm 50 \text{ mA}$
DC OUTPUT SOURCE OR SINK CURRENT per Output Pin, $I_0$ (for $V_0 > -0.5$ V or $V_0 < V_{CC} + 0.5$ V) $\pm 50$ mA
DC V <sub>CC</sub> or GROUND CURRENT (I <sub>CC</sub> or I <sub>GND</sub> )
POWER DISSIPATION PER PACKAGE (Pa):
For T <sub>A</sub> = -55 to +100°C (PACKAGE TYPE E)
For T <sub>A</sub> = +100 to +125°C (PACKAGE TYPE E)
For T <sub>A</sub> = -55 to +70°C (PACKAGE TYPE M) 400 mw
For T <sub>A</sub> = +70 to +125°C (PACKAGE TYPE M) Derate Linearly at 6 mW/°C to 70 mW
OPERATING-TEMPERATURE RANGE (T <sub>A</sub> )55 to ±125°C
STORAGE TEMPERATURE (T <sub>stg</sub> )65 to +150°C
LEAD TEMPERATURE (DURING SOLDERING):
At distance $1/16 \pm 1/32$ in. $(1.59 \pm 0.79 \text{ mm})$ from case for 10 s maximum
Unit inserted into PC board min. thickness 1/16 in. (1.59 mm) with solder contacting lead tips only +300°C
*For up to 4 outputs per device; add $\pm$ 25 mA for each additional output.

### RECOMMENDED OPERATING CONDITIONS:

For maximum reliability, normal operating conditions should be selected so that operation is always within the following ranges:

		/ LIN	IITS	LIMITS
CHARACTERISTIC	75 34	MIN.	MAX.	UNITS
Supply-Voltage Range, V <sub>CC</sub> *:  (For T <sub>A</sub> = Full Package-Temperature Range)  AC Types  ACT Types	Com.	1.5 4.5	5.5 5.5	V
DC Input or Output Voltage, V <sub>1</sub> , V <sub>0</sub>		0	Vcc	V
Operating Temperature, T <sub>A</sub>		-55	+125	°C
Input Rise and Fall Slew Rate, dt/dv at 1.5 V to 3 V (AC Types) at 3.6 V to 5.5 V (AC Types) at 4.5 V to 5.5 V (ACT Types)		0 0 0	50 20 10	ns/V ns/V ns/V

<sup>\*</sup>Unless otherwise specified, all voltages are referenced to ground.

CD54/74AC/ACT374

### **TERMINAL ASSIGNMENT DIAGRAMS**



### STATIC ELECTRICAL CHARACTERISTICS: AC Series

						AMBIENT TEMPERATURE (TA) - °C					
CHARACTERIST	ICS	TEST CO	NDITIONS	V <sub>cc</sub>	+	25	-40 (	o +85	-55 to +125		UNITS
		(V)	I <sub>o</sub> (mA)	(V)	MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
High-Level Input				1.5	1.2		1.2	_	1.2	<b> </b>	1
Voltage	ViH			3	2.1	_	2.1	T -	2.1	_	7 v
				5.5	3.85		3.85		3.85	T —	7
Low-Level Input				1.5		0.3	<u> </u>	0.3	_	0.3	
Voltage	V <sub>IL</sub>			3		0.9	_	0.9		0.9	7 v
				5.5	_	1.65	_	1.65	-	1.65	1
High-Level Output			-0.05	1.5	1.4	_	1.4	_	1.4	T -	
Voltage	V <sub>OH</sub>	ViH	-0.05	3	2.9		2.9		2.9		1
		or	-0.05	4.5	4.4	_	4.4	_	4.4	_	1
		VIL	-4	3	2.58	_	2.48	_	2.4	_	V
			-24	4.5	3.94	_	3.8	_	3.7	_	1
		#, * {	-75	5.5	l –	_	3.85	_	_	_	1
		<b>\biggreup</b>	-50	5.5	_		2-75°		3.85		1
Low-Level Output			0.05	1.5	_	=0.1	- 4	0.1	_	0.1	
Voltage	Vol	V <sub>IH</sub>	0.05	3	-3	0.1	(4)	0.1	_	0.1	1
		or	0.05	4.5	3	0.1	10	0.1	_	0.1	1
		VIL	12	3	-	0.36	_	0.44	_	0.5	V
			24	4.5		0.36	_	0.44	_	0.5	
		#, ★	75	5.5	3 —	_	-	1.65	_	_	1
		",	50	5.5	_	_	-	_	_	1.65	
Input Leakage Current	I,	V <sub>∞</sub> or GND		5.5		±0.1	_	±1	-	±1	μΑ
3-State Leakage Current	loz	V <sub>IH</sub>									
	1	VIL					l				
		Vo=		5.5	-	±0.5	_	±5		±10	μΑ
		Vcc	İ			:			ĺ		
		or				-					
	]	GND		1						İ	
Quiescent Supply Current, MSI	loc	V <sub>∞</sub> or GND	0	5.5	-	8	-	80	_	160	μΑ

<sup>#</sup>Test one output at a time for a 1-second maximum duration. Measurement is made by forcing current and measuring voltage to minimize power dissipation.

\* Test verifies a minimum 50-ohm transmission-line-drive capability at +85° C, 75 ohms at +125° C.

Technical Data

## CD54/74AC374, CD54/74AC534 CD54/74ACT374, CD54/74ACT534

STATIC ELECTRICAL CHARACTERISTICS: ACT Series

	- · · · ·				A	MBIENT	TEMPE	RATURE	(T <sub>A</sub> ) - °C	>	
CHARACTERISTIC	cs	TEST CON	IDITIONS	V <sub>cc</sub>	+2	25	-40 to	+85	-55 to	+125	UNITS
		V <sub>1</sub> l <sub>0</sub> (mA)		(V)	MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
High-Level Input Voltage	Vін			4.5 to 5.5	2	_	2		2	_	v
Low-Level Input Voltage	V <sub>IL</sub>			4.5 to 5.5	_	0.8		0.8	_	0.8	v
High-Level Output		V <sub>IH</sub>	-0.05	4.5	4.4	_	4.4		4.4		
Voltage	V <sub>ОН</sub>	or V <sub>IL</sub>	-24	4.5	3.94	1	3.8		3.7		V
	#, * {	-75	5.5	_	_	3.85					
		<b>"</b> ' {	-50	5.5	1	_			3.85	<u> </u>	
Low-Level Output	v-Level Output	V <sub>IH</sub>	0.05	4.5		0.1		0.1		0.1	1
Voltage V <sub>OL</sub>	or V <sub>IL</sub>	24	4.5	_	0.36		0.44		0.5	l v	
		#. * {	75	5.5			- 4	1.65			1
		"' {	50	5.5	_		, <u>mi</u>	M —		1.65	ļ
Input Leakage Current	~ I <sub>1</sub>	V <sub>cc</sub> or GND		5.5	90	±0.1	30-	H	_	±1	μΑ
3-State Leakage Current	loz	V <sub>IH</sub> or V <sub>IL</sub> V <sub>O</sub> =		5.5		±0.5	_	±5	_	±10	μΑ
		V <sub>cc</sub> or GND									
Quiescent Supply Current, MSI	Icc	V <sub>cc</sub> or GND	0	5.5		8		80	_	160	μΑ
Additional Quiescent Current per Input P TTL Inputs High 1 Unit Load		V <sub>cc</sub> -2.1		4.5 to 5.5		2.4	_	2.8	_	3	mA

<sup>#</sup>Test one output at a time for a 1-second maximum duration. Measurement is made by forcing current and measuring voltage to minimize

### **ACT INPUT LOADING TABLE**

INPUT	UNIT LOADS*
D, ŌĒ	0.7
ĊР	1.17

<sup>\*</sup>Unit load is  $\Delta l_{CC}$  limit specified in Static Characteristics Chart, e.g., 2.4 mA max. @ 25° C.

power dissipation.

\* Test verifies a minimum 50-ohm transmission-line-drive capability at +85°C, 75 ohms at +125°C.

#### PREREQUISITE FOR SWITCHING: AC Series

		V <sub>cc</sub> (V)	AMBI	(A) - °C	UNITS		
CHARACTERISTICS	SYMBOL		-40 to +85			-55 to +125	
		(*)	MiN.	MAX.	MIN.	MAX.	1
Clock Pulse Width	tw	1.5 3.3* 5†	44 4.9 3.5		50 5.6 4	<u>-</u>	ns
Setup Time Data to Clock	tsu	1.5 3.3 5	2 2 2	_ 	2 2 2		ns
Hold Time Data to Clock	t <sub>H</sub>	1.5 3.3 5	2 2 2		2 2 2		ns
Maximum Clock Frequency	f <sub>MAX</sub>	1.5 3.3 5	11 101 143		10 89 125		MHz

\*3.3 V: min. is @ 3 V †5 V: min. is @ 4.5 V

### SWITCHING CHARACTERISTICS: AC Series; $t_r$ , $t_t$ = 3 ns, $C_t$ = 50 pF

		Ī	AMBIE	NT TEMPE	RATURE (	Γ <sub>A</sub> ) - °C		
CHARACTERISTICS	SYMBOL	V <sub>cc</sub> (V)	-40 to +85		-55 t	0 +125	UNITS	
		(*/	MIN.	MAX.	MIN.	MAX.	7	
Propagation Delays: Clock to Q AC374	t <sub>PLH</sub> t <sub>PHL</sub>	1.5 3.3* 5†	3.9	123 13.7 9.8	— 3.8 2.7	135 15.1 10.8	ns	
Clock to Q AC534	ŧегн Фнг	1.5 3.3 5	- 4.1 2.9	128 14.4 10.3	_ 4 2.8	141 15.8 11.3	ns	
Output Enable to Q, Q	tezi tezh	1.5 3.3 5	 5.6 3.7	165 19.8 13.2	 5.5 3.6	181 21.8 14.5	пѕ	
Output Disable to Q, Q	t <sub>PLZ</sub> t <sub>PHZ</sub>	1.5 3.3 5	4.7 3.7	165 16.5 13.2	4.5 3.6	181 18.1 14.5	ns	
Power Dissipation Capacitance	CeD§	_	67 <b>T</b>	yp.	67	Тур.	pF	
Min. (Valley) V <sub>OH</sub> During Switching of Other Outputs (Output Under Test Not Switching)	V <sub>онv</sub> See Fig. 1	5	4 Typ. @ 25°C				V	
Max. (Peak) V <sub>OL</sub> During Switching of Other Outputs (Output Under Test Not Switching)	V <sub>OLP</sub> See Fig. 1	5		1 Тур. (	⊕ 25°C		٧	
Input Capacitance	Cı	_		10		10	ρF	
3-State Output Capacitance	Co	_	_	15	_	15	pF	

\*3.3 V: min. is @ 3.6 V max. is @ 3 V †5 V: min. is @ 5.5 V

max. is @ 4.5 V

§CPD is used to determine the dynamic power consumption, per flip flop.

 $P_D = C_{PD} V_{CC}^2 f_i + \Sigma V_{CC}^2 f_0 C_L$  where  $f_i = input frequency$ 

 $f_0 = \text{output frequency}$ 

 $C_L = \text{output load capacitance}$ 

V<sub>cc</sub> = supply voltage.

Technical Data

# CD54/74AC374, CD54/74AC534 CD54/74ACT374, CD54/74ACT534

PREREQUISITE FOR SWITCHING: ACT Series

-	` '	A <sup>cc</sup>	AMBI	Ϊ,			
CHARACTERISTICS	SYMBOL		-40 to +85		-55 to +125		UNITS
·			MIN.	MAX.	- MIN.	MAX.	
Clock Pulse Width	t <sub>w</sub>	5†	3.9	_	4.5	_	ns
Setup Time Data to Clock	tsu	5	2	_	2	_	ns
Hold Time Data to Clock	t <sub>H</sub>	5	2.6	_	3	_	ns
Maximum Clock Frequency	f <sub>MAX</sub>	5	125	_	110	-	MHz

15 V: min. is @ 4.5 V

### SWITCHING CHARACTERISTICS: ACT Series; t, t, = 3 ns, C, = 50 pF

	T	T	AMBII	ENT TEMPE	RATURE (1	(.) - °C	<u> </u>
CHARACTERISTICS	SYMBOL	V <sub>cc</sub> (V)		o +85	· · · · · · · · · · · · · · · · · · ·	+125	UNITS
OTTAIN TENS 1103	37111500	(V)	MIN.	MAX.	MIN.	MAX.	] .
Propagation Delays: Clock to Q ACT374	teli.	5†	2.9	10.2	2.8	11.2	ns
Clock to Q ACT534	t <sub>PLH</sub>	5	3 3	10.6	2.9	11.7	ns
Output Enable and Disable to Q ACT374	telz tenz t <sub>ezt</sub> t <sub>ezn</sub>	5	3,7	13.2	3.6	14.5	ns
Output Enable and Disable to Q ACT534	tplz tpHz tpzl tpzH	5	3.7	13.2	3.6	14.5	ns
Power Dissipation Capacitance	C <sub>PD</sub> §	_	67	Гур.	67 Typ.		ρF
Min. (Valley) V <sub>OH</sub> During Switching of Other Outputs (Output Under Test Not Switching)	V <sub>онv</sub> See Fig. 1	5		4 Typ. @ 25°C			V
Max. (Peak) V <sub>oL</sub> During Switching of Other Outputs (Output Under Test Not Switching)	V <sub>OLP</sub> See Fig. 1	5		1 Typ. @ 25°C			V
Input Capacitance	C <sub>i</sub>	-		10		10	pF
3-State Output Capacitance	Co	_	_	15	_	15	ρF

†5 V: min. is @ 5.5 V max. is @ 4.5 V

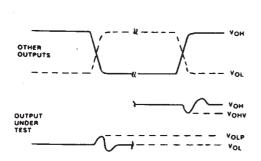
 $C_{PD}$  is used to determine the dynamic power consumption, per flip flop.  $P_D = C_{PD} \ V_{CC}^2 \ f_i + V_{CC}^2 \ f_0 \ C_L + V_{CC} \ \Delta I_{CC} \ where \quad f_i = input \ frequency$ 

fo = output frequency

C<sub>L</sub> = output load capacitance

 $V_{CC}$  = supply voltage.

#### PARAMETER MEASUREMENT INFORMATION



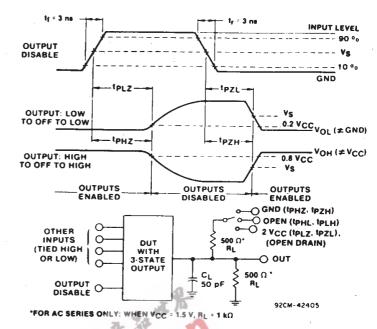
- NOTES:

  1. VOHY AND VOLP ARE MEASURED WITH RESPECT TO A GROUND REFERENCE NEAR THE OUTPUT UNDER TEST.
- REFERENCE MEAR THE OUTPUT UNDER TEST.

  2. INPUT PULSES HAVE THE FOLLOWING CHARACTERISTICS:
  PAR § 1 MHz, t<sub>1</sub> = 3 ns, t<sub>1</sub> = 3 ns, SKEW 1 ns.

  3. R.F. FIXTURE WITH 700-MHz DESIGN RULES REQUIRED.
  IC SHOULD BE SOLDERED INTO TEST BOARD AND BYPASSED WITH 0.1 JF CAPACITOR. SCOPE AND PROBES REQUIRE
  700-MHz BANDWIDTH.

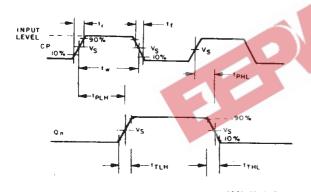
9205-42406



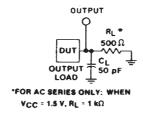
\*For AC series only: When  $V_{CC} = 1.5V$ ,  $R_L = 1 k\Omega$ 

Fig. 1 - Simultaneous switching transient waveforms.

Three-state propagation delay waveforms and test circuit.



INPUT LEVEL 1<sub>H</sub>(L) C₽ 92CS - 36954R1



9205 - 42389

Fig. 3 - Propagation delay times and test circuit.

	CD54/74AC	CD54/74ACT
Input Level	V <sub>cc</sub>	3 V
Input Switching Voltage, Vs	0.5 V <sub>CC</sub>	1.5 V
Output Switching Voltage, Vs	0.5 V <sub>cc</sub>	0.5 V <sub>cc</sub>





17-Aug-2007

### **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
CD54AC374F3A	ACTIVE	CDIP	J	20	1	TBD	Call TI	N / A for Pkg Type
CD54ACT374F3A	ACTIVE	CDIP	J	20	1	TBD	Call TI	N / A for Pkg Type
CD54ACT534F3A	OBSOLETE	CDIP	J	20		TBD	Call TI	Call TI
CD74AC374E	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74AC374EE4	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74AC374M	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74AC374M96	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74AC374M96E4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74AC374M96G4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74AC374ME4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74AC374MG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74AC534M96	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74AC534M96E4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74AC534M96G4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74ACT374E	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74ACT374EE4	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74ACT374M	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74ACT374M96	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74ACT374M96E4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74ACT374M96G4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74ACT374ME4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74ACT374MG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

 $<sup>^{(1)}</sup>$  The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.



### PACKAGE OPTION ADDENDUM

17-Aug-2007

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <a href="http://www.ti.com/productcontent">http://www.ti.com/productcontent</a> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

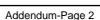
**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

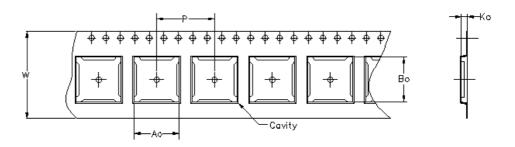
(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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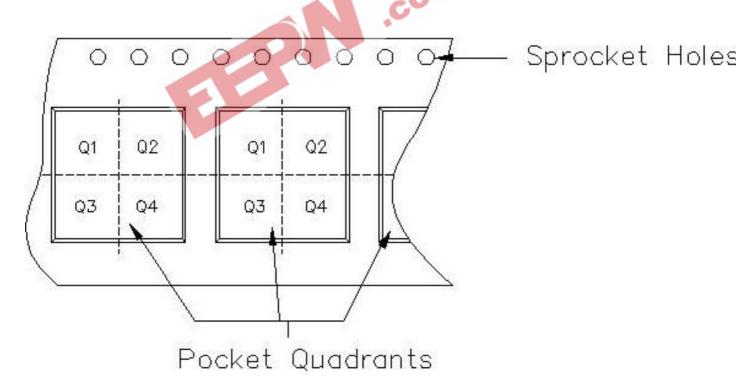






Carrier tape design is defined largely by the component lentgh, width, and thickness

Ao = Dimension designed to accommodate the component width.							
Bo = Dimension designed to accommodate the component length.							
Ko = Dimension designed to accommodate the component thickness.							
W = Overall width of the carrier tape.							
P = Pitch between successive cavity centers							



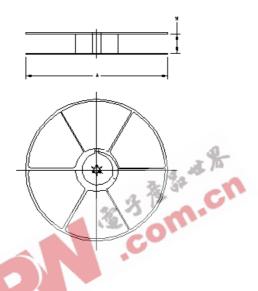
### TAPE AND REEL INFORMATION



### **PACKAGE MATERIALS INFORMATION**

30-Apr-2007

Device	Package	Pins	Site	Reel Diameter (mm)	Reel Width (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74AC374M96	DW	20	MLA	330	24	10.8	13.0	2.7	12	24	Q1
CD74AC534M96	DW	20	MLA	330	24	10.8	13.0	2.7	12	24	Q1
CD74ACT374M96	DW	20	MLA	330	24	10.8	13.0	2.7	12	24	Q1



### TAPE AND REEL BOX INFORMATION

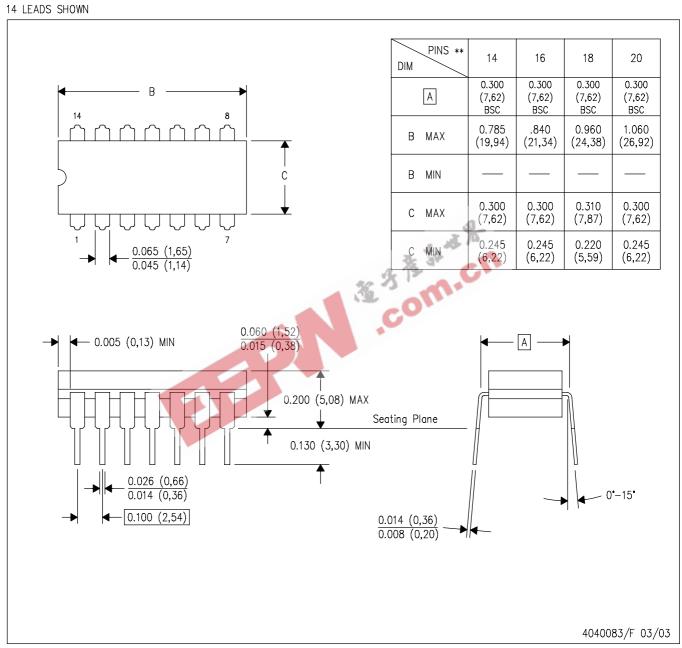
Device	Package	Pins	Site	Length (mm)	Width (mm)	Height (mm)
CD74AC374M96	DW	20	MLA	333.2	333.2	31.75
CD74AC534M96	DW	20	MLA	333.2	333.2	31.75
CD74ACT374M96	DW	20	MLA	333.2	333.2	31.75



### **PACKAGE MATERIALS INFORMATION**

30-Apr-2007





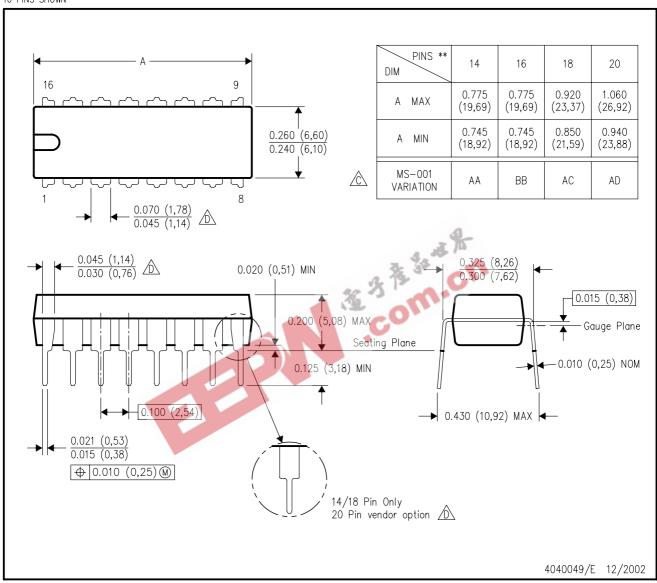
NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

### N (R-PDIP-T\*\*)

### PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



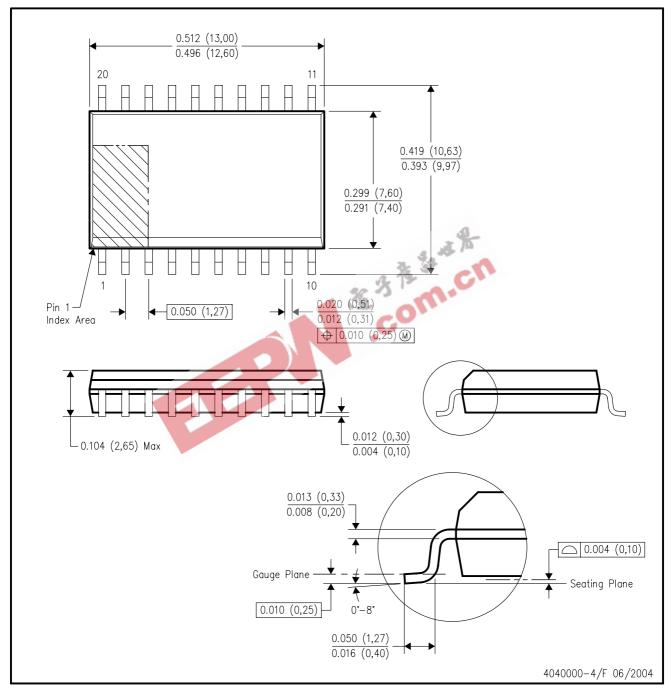
NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



### DW (R-PDSO-G20)

### PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AC.



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